FAIRCHILD SEMICONDUCTOR®

April 2007

FFPF08H60S
Hyperfast 2 Rectifier

Features

- High Speed Switching (t_{rr}=45ns(Max.) @ I_F=8A)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- Low Forward Voltage(V_F=2.1V(Max.) @ I_F=8A)

Applications

- General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits

8A, 600V Hyperfast 2 Rectifier

The FFPF08H60S is hyperfast2 rectifier (t_{rr}=45ns(Max.) @ I_F=8A). it has half the recovery time of ultrafast rectifier and is silicon nitride passivated ion-implanted epitaxial planar construction.

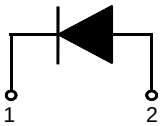
This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power swithching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Pin Assignments



TO-220F-2L

1. Cathode 2. Anode



1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ T_C = 105 °C	8	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	A
T_J, T_{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C

Thermal Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.4	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F08H60S	FFPF08H60STU	TO-220F	-	-	50

©2006 Fairchild Semiconductor Corporation

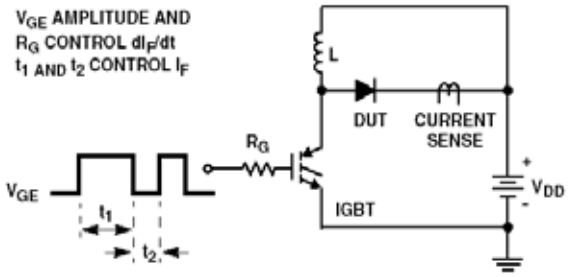
Electrical Characteristics T_C = 25°C unless otherwise noted

Parameter	Conditions		Min.	Typ.	Max	Units
V_{FM}[1]	I_F = 8A I_F = 8A	T_C = 25 °C T_C = 125 °C	- -	- -	2.1 1.7	V V
I_{RM}[1]	V_R = 600V V_R = 600V	T_C = 25 °C T_C = 125 °C	- -	- -	100 200	μA μA
t_{rr}	I_F =1A, di/dt = 100A/μs, V_{CC} = 30V I_F =8A, di/dt = 100A/μs, V_{CC} = 390V	T_C = 25 °C T_C = 25 °C	- -	- -	35 45	ns ns
t_a t_b Q_{rr}	I_F =8A, di/dt = 100A/μs, V_{CC} = 390V	T_C = 25 °C T_C = 25 °C T_C = 25 °C	- - -	15 16 18.6	- - -	ns ns nC
W_{AVL}	Avalanche Energy (L = 40mH)		20	-	-	mJ

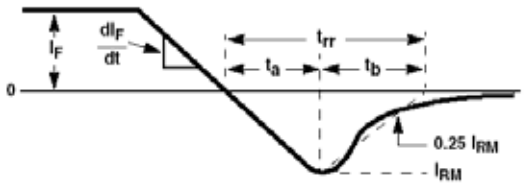
Notes:

1. Pulse : Test Pulse width = 300μs, Duty Cycle = 2%

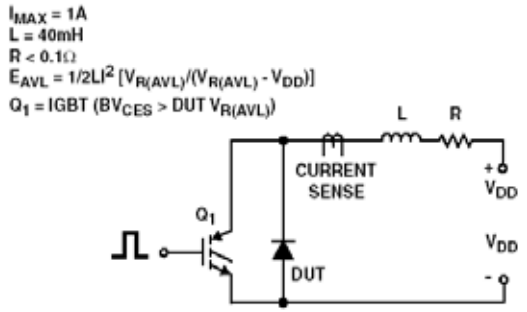
Test Circuit and Waveforms



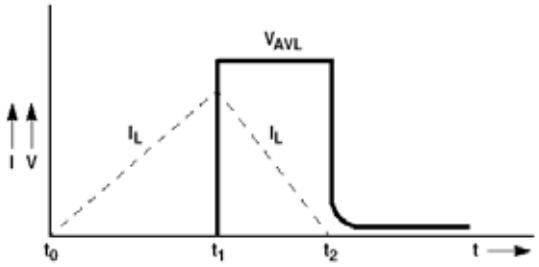
t_{rr} TEST CIRCUIT



t_{rr} WAVEFORMS AND DEFINITIONS



AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics T_C = 25°C unless otherwise noted

Figure 1. Typical Forward Voltage Drop

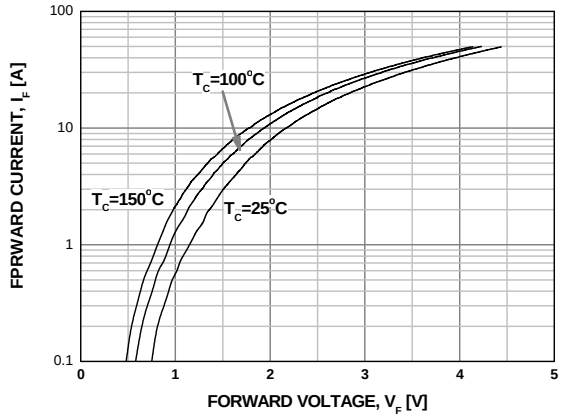


Figure 2. Typical Reverse Current

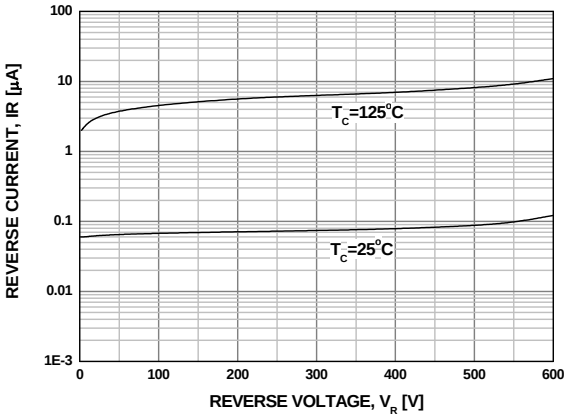


Figure 3. Typical Junction Capacitance

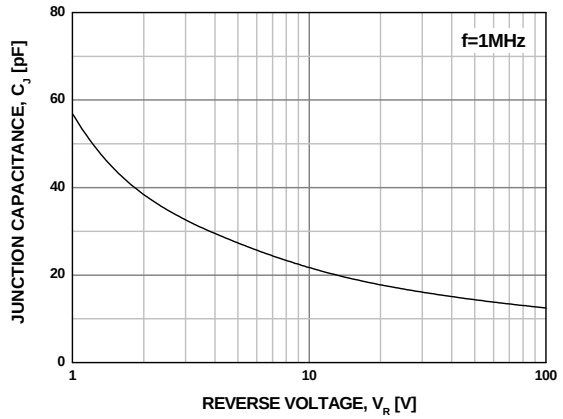


Figure 4. Typical Reverse Recovery Time

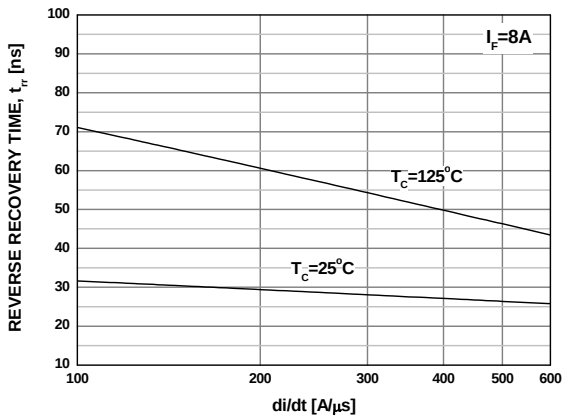


Figure 5. Typical Reverse Recovery Current

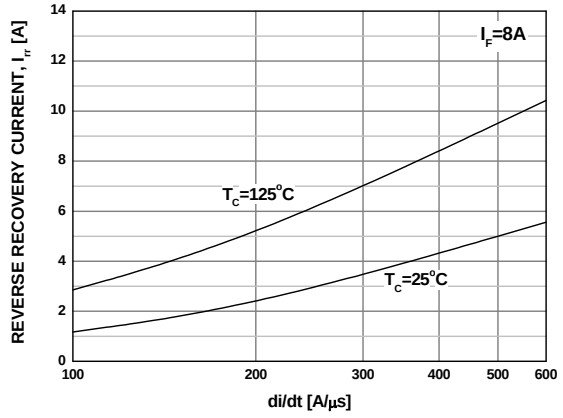
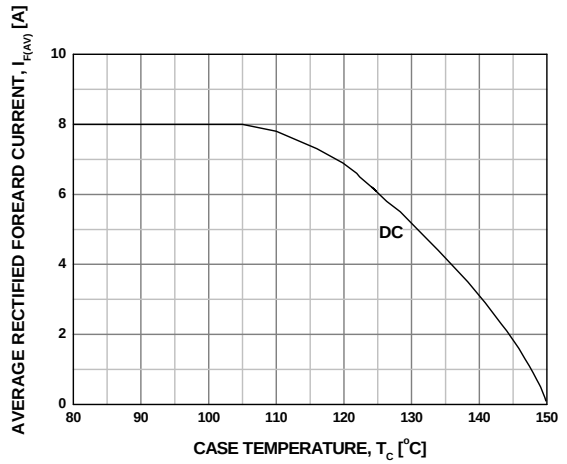
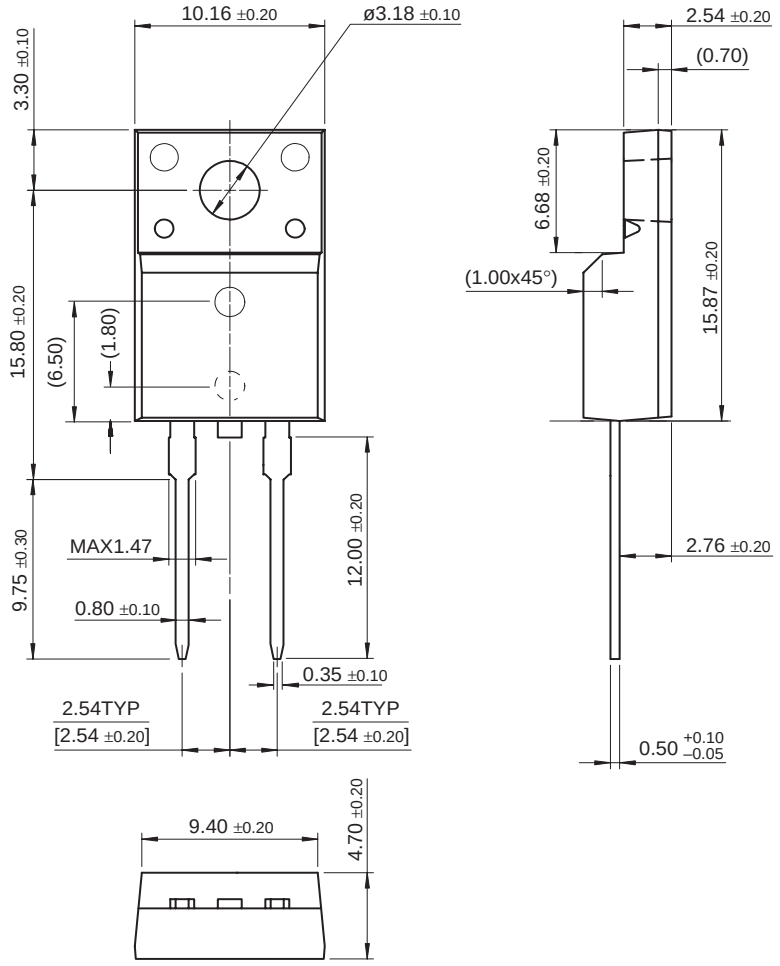


Figure 6. Forward Current Deration Curve



Mechanical Dimensions

TO-220F 2L



Dimensions in Millimeters

FAIRCHILD
SEMICONDUCTOR®

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx®	GlobalOptoisolator™	Power247®	SyncFET™
Across the board. Around the world.™	GTO™	PowerEdge™	TCM™
ActiveArray™	HiSeC™	PowerSaver™	The Power Franchise®
Bottomless™	*i-Lo*™	PowerTrench®	™
Build it Now™	ImpliedDisconnect™	Programmable Active Droop™	
CoolFET™	IntelliMAX™	QFET®	TinyBoost™
CROSSVOLT™	ISOPLANAR™	QS™	TinyBuck™
CTL™	MICROCOUPLER™	QT Optoelectronics™	TinyLogic®
Current Transfer Logic™	MicroPak™	Quiet Series™	TINYOPTO™
DOME™	MICROWIRE™	RapidConfigure™	TinyPower™
E^2CMOS™	MSX™	RapidConnect™	TinyWire™
EcoSPARK®	MSXPro™	ScalarPump™	TruTranslation™
EnSigna™	OCX™	SMART START™	µSerDes™
FACT Quiet Series™	OCXPro™	SPM®	UHC®
FACT®	OPTOLOGIC®	STEALTH™	UniFET™
FAST®	OPTOPLANAR®	SuperFET™	VCX™
FASTr™	PACMAN™	SuperSOT™-3	Wire™
FPS™	POP™	SuperSOT™-6	
FRFET®	Power220®	SuperSOT™-8	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

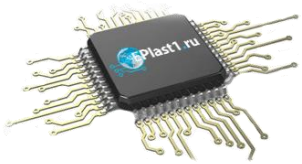
Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)
Факс: 8 (812) 320-02-42
Электронная почта: org@eplast1.ru
Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.